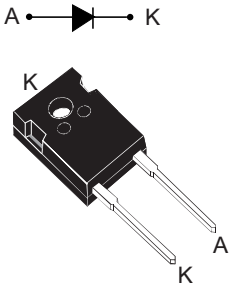
STPSC30G12-Y

Datasheet

Automotive 1200 V, 30 A power Schottky high surge silicon carbide diode



DO-247 LL

Features

- AEC-Q101 qualified and PPAP capable
- None or negligible reverse recovery
- Switching behavior independent of temperature
- Robust high voltage periphery
- Operating T_j from -55 °C to 175 °C
- Avalanche energy rated
- ECOPACK2 compliant component

Applications

- Boost PFC
- HEV/EV OBC (On board battery chargers)
- EV Charging station

Description

The SiC diode, available in DO-247 with long leads, is an ultrahigh performance power Schottky rectifier. It is manufactured using a silicon carbide substrate. The wide band-gap material allows the design of a low V_F Schottky diode structure with a 1200 V rating. Thanks to the Schottky construction, no recovery is shown during turn-off and ringing patterns are negligible. The minimal capacitive turn-off behavior is independent of temperature.

Based on latest technology optimization, this diode has an improved forward surge current capability, making it ideal for use in PFC, where this ST SiC diode boosts the performance in hard switching conditions while bringing robustness to the design. Its high forward surge capability ensures a good robustness during transient phases.

Product label
SUSTAINABLE TECHNOLOGY

Product status link
STPSC30G12-Y

Product summary	
$I_{F(AV)}$	30 A
V_{RRM}	1200 V
T_j (max.)	175 °C
V_F (typ.)	1.35 V

1 Characteristics

Table 1. Absolute ratings (limiting values at 25 °C, unless otherwise specified)

Symbol	Parameter			Value	Unit
V_{RRM}	Repetitive peak reverse voltage (T_j = -40 °C to +175 °C)			1200	V
E_{AS} (1)	Single pulse avalanche energy, starting T_j = 25 °C, I_{AS} = 7.7 A, L = 10 mH			296	mJ
$I_{F(RMS)}$	Forward rms current			79	A
$I_{F(AV)}$	Average forward current	T_c = 145 °C, δ = 1		30	A
I_{FRM}	Repetitive peak forward current	T_c = 145 °C, T_j = 175 °C, δ = 0.1, f_{sw} > 10 kHz		119	A
I_{FSM}	Surge non repetitive forward current	t_p = 10 ms sinusoidal	T_c = 25 °C	250	A
			T_c = 150 °C	225	
		t_p = 10 µs square	T_c = 25 °C	1550	
T_{stg}	Storage temperature range			-65 to +175	°C
T_j	Operating junction temperature range			-55 to +175	°C

1. *Please refer to Figure 1.*

Table 2. Thermal resistance parameters

Symbol	Parameter	Value		Unit
		Typ.	Max.	
$R_{th(j-c)}$	Junction to case	0.30	0.45	°C/W

For more information, please refer to the following application note:

- AN5088 : Rectifiers thermal management, handling and mounting recommendations

Table 3. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Typ.	Max.	Unit
I_R (1)	Reverse leakage current	T_j = 25 °C	$V_R = V_{RRM}$	-	15	225	µA
		T_j = 150 °C		-	50	750	
		T_j = 175 °C			112		
V_F (2)	Forward voltage drop	T_j = 25 °C	I_F = 30 A	-	1.35	1.50	V
		T_j = 150 °C		-	1.75	2.10	
		T_j = 175 °C			1.90		

1. *Pulse test: t_p = 10 ms, δ < 2%*
2. *Pulse test: t_p = 380 µs, δ < 2%*

To evaluate the conduction losses, use the following equation:

$P = 0.924 \times I_{F(AV)} + 0.039 \times I_F{}^2{}_{(RMS)}$

For more information, please refer to the following application notes related to the power losses:

- AN604: Calculation of conduction losses in a power rectifier
- AN4021: Calculation of reverse losses on a power diode

Table 4. Dynamic electrical characteristics

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
Q_{Cj} (1)	Total capacitive charge	V_R = 800 V	-	149	-	nC
C_j	Total capacitance	V_R = 0 V, T_c = 25 °C, F = 1 MHz	-	2272	-	pF
		V_R = 800 V, T_c = 25 °C, F = 1 MHz	-	108	-	

1. *Most accurate value for the capacitive charge:* $Q_{cj}(V_R) = \int_0^{V_R} C_j(V)dV$

Figure 1. Current and voltage waveforms for avalanche energy test across D.U.T (device under test)

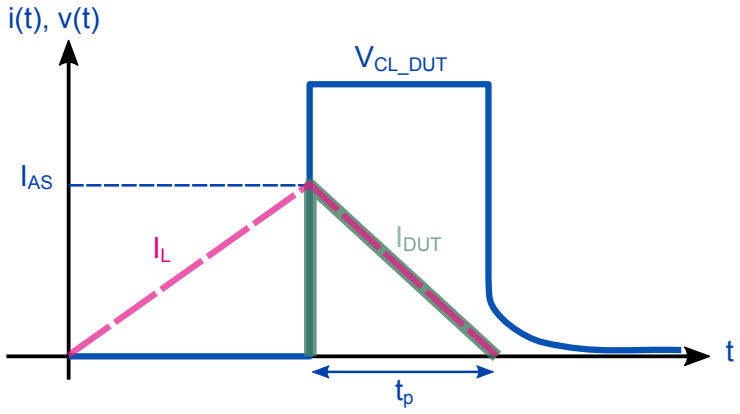


Figure 2. Thermal transient impedance model circuit of the diode – $Z_{th(j-c)}$

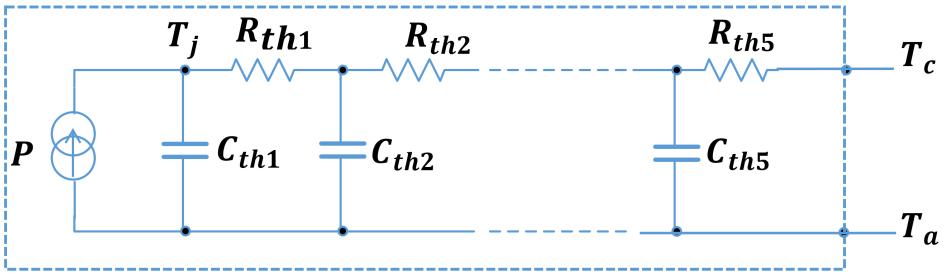


Table 5. Components typical values of the diode thermal transient impedance model $Z_{th(j-c)}$

Ref.	Value (K/W)	Ref.	Value (J/K)
R_{th1}	19.6m	C_{th1}	4.88m
R_{th2}	75.7m	C_{th2}	3.23m
R_{th3}	102m	C_{th3}	22.2m
R_{th4}	79.1m	C_{th4}	109m
R_{th5}	24.4m	C_{th5}	1.43

1.1 Characteristics (curves)

Figure 3. Forward voltage drop versus forward current (typical values)

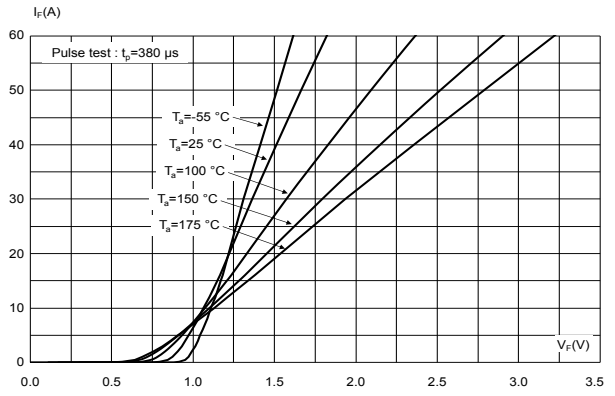


Figure 4. Reverse leakage current versus reverse voltage applied (typical values)

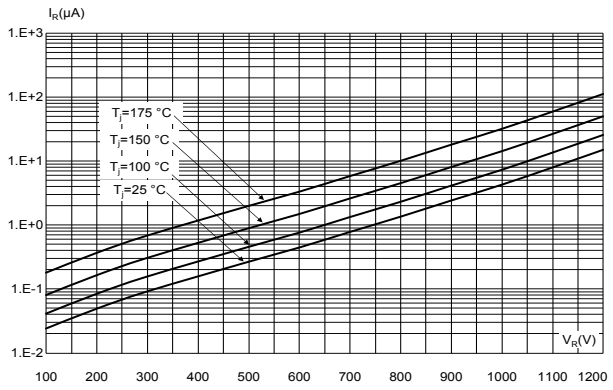


Figure 5. Peak forward current versus case temperature

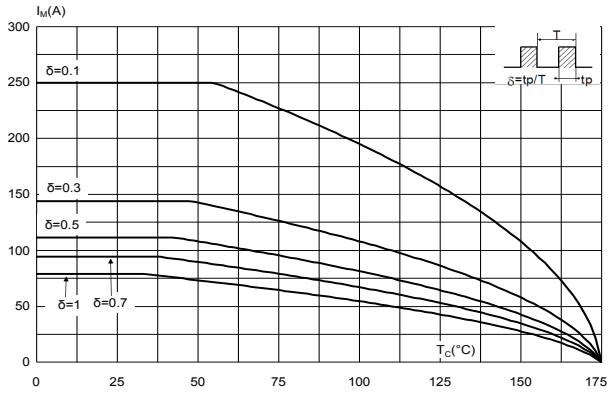


Figure 6. Junction capacitance versus reverse voltage applied (typical values)

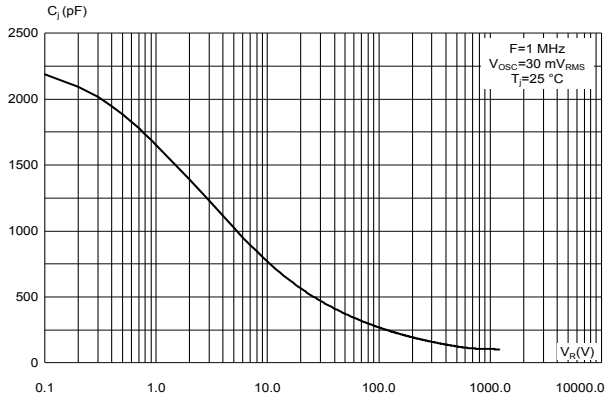


Figure 7. Relative variation of thermal impedance junction to case versus pulse duration

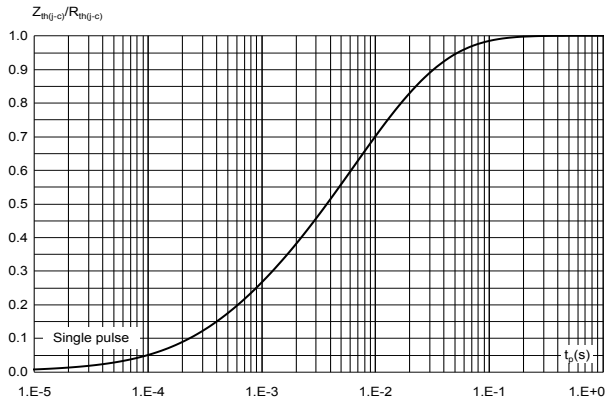


Figure 8. Non-repetitive peak surge forward current versus pulse duration (sinusoidal waveform)

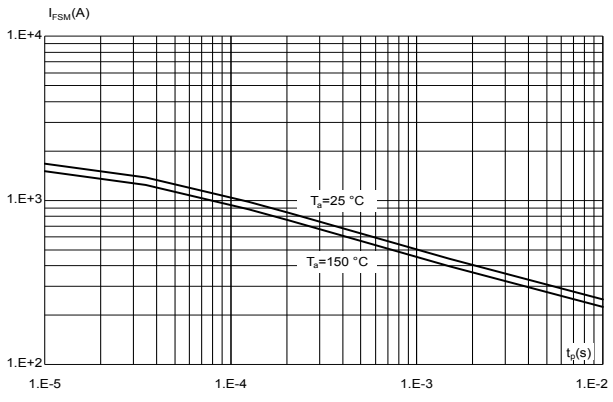
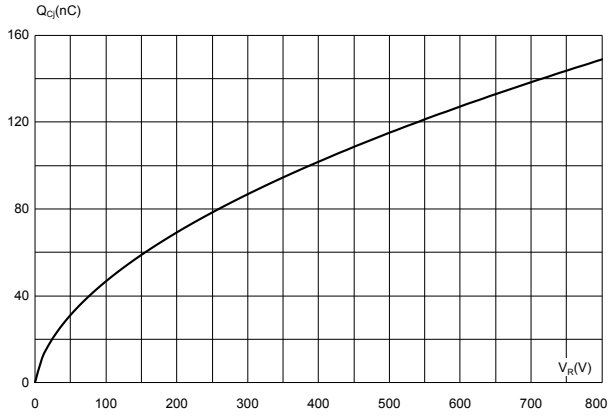


Figure 9. **Total capacitive charges versus reverse voltage applied (typical values)**



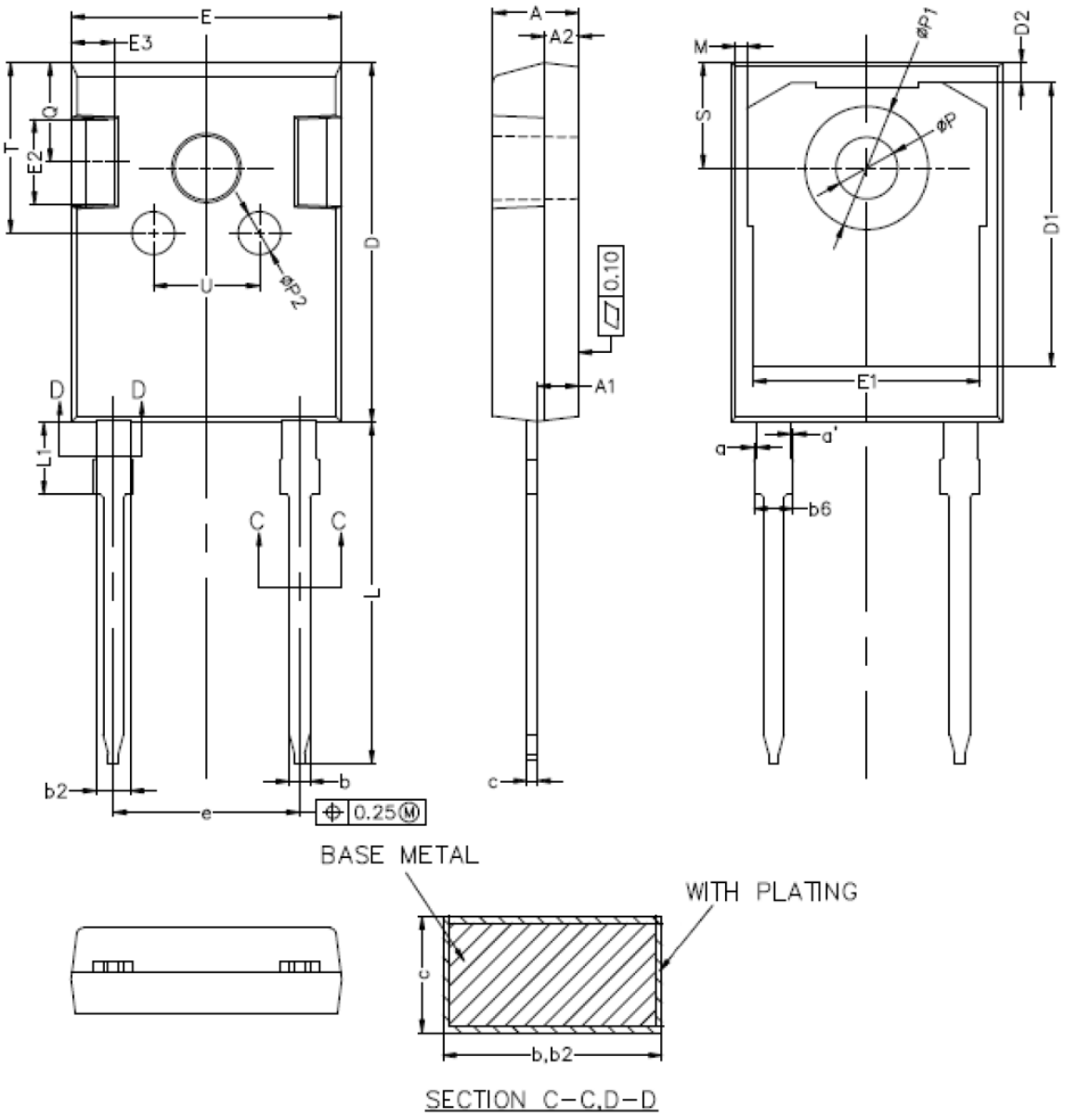
2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

2.1 DO-247 LL package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.8 N·m
- Maximum torque value: 1.0 N·m

Figure 10. DO-247 LL package outline



Note: This package drawing may slightly differ from the physical package. However, all the specified dimensions are guaranteed.

Table 6. DO-247 LL package mechanical data

Ref.	Dimensions					
	Millimeters			Inches (for reference only)		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.90	5.00	5.10	0.192	0.197	0.201
A1	2.31	2.41	2.51	0.090	0.095	0.099
A2	1.90	2.00	2.10	0.074	0.079	0.083
a	0.00		0.15	0.000		0.006
a'	0.00		0.15	0.000		0.006
b	1.16		1.29	0.045		0.051
b2	1.96		2.06	0.077		0.082
b6			2.25			0.089
c	0.59		0.66	0.023		0.026
D	20.90	21.00	21.10	0.822	0.827	0.831
D1	16.25	16.55	16.85	0.639	0.652	0.664
D2	1.05	1.20	1.35	0.041	0.047	0.054
E	15.70	15.80	15.90	0.618	0.622	0.626
E1	13.06	13.26	13.46	0.514	0.522	0.530
E2	4.90	5.00	5.10	0.192	0.197	0.201
E3	2.40	2.50	2.60	0.094	0.098	0.103
e	10.78	10.88	10.98	0.424	0.428	0.433
L	19.80	19.92	20.10	0.779	0.784	0.792
L1	3.93		4.46	0.154		0.176
M	0.35		0.95	0.013		0.038
P	3.50	3.60	3.70	0.137	0.142	0.146
P1	7.00		7.40	0.275		0.292
P2	2.40	2.50	2.60	0.094	0.098	0.103
Q	5.60		6.00	0.220		0.237
S	6.05	6.15	6.25	0.238	0.242	0.247
T	9.80		10.20	0.385		0.402
U	6.00		6.40	0.236		0.252

3 Ordering information

Table 7. **Ordering information**

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STPSC30G12WLY	STPSC30G12WLY	DO-247LL	5.9 g	30	Tube

Revision history

Table 8. **Document revision history**

Date	Revision	Changes
09-Nov-2022	1	Initial release.